

/ Descriptions

PDFN3×3A-8L N MOS
N-Channel Enhancement Mode Field Effect Transistor in a PDFN3×3A-8L Plastic Package.

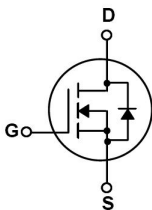
/ Features

$V_{DS} (V) = 60V$
 $I_D = 24 A (V_{GS} = \pm 20V)$
 $R_{DS(ON)}@10V \leq 13mR(Typ.11.5mR)$
HF Product.

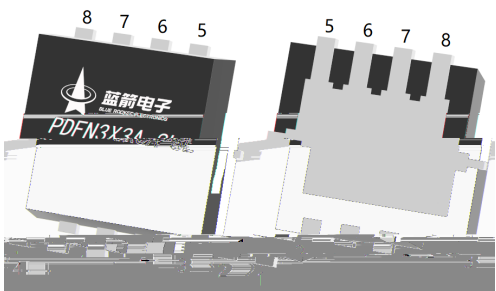
/ Applications

DC/DC
These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.

/ Equivalent Circuit



/ Pinning



出脚	定义
Pin1	S
Pin2	S
Pin3	S
Pin4	G
Pin5	D
Pin6	D
Pin7	D
Pin8	D

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	60	V
Drain Current		$I_D(T_C=25)$	24	A
Drain Current - Pulsed		I_{DM}	90	A
Gate-Source Voltage		V_{GS}	± 20	V
Single Pulsed Avalanche Energy		E_{AS}	70	mJ
Avalanche Current		I_{AS}	20	A
Power Dissipation		$P_D(T_C=25)$	24	W
Operating and Storage Temperature Range		T_J, T_{stg}	-55 to 150	$^{\circ}\text{C}$
Junction-to-Ambient	$t \leq 10$	R_{JA}	30	/W
Junction-to-Ambient	Steady-State		55	
Junction-to-Case	Steady-State	R_{JC}	5.2	

BRCS120N06YB

Rev.B Oct.-2024

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250 A$	60	64		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V$ $V_{GS}=0V$			1	A
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 0.1	A
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250 A$	1.0	1.6	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=20A$		11.5	13	m
		$V_{GS}=4.5V$ $I_D=10A$		15.5	18	m
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=1A$			1.2	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		1010		pF
Output Capacitance	C_{oss}			250		
Reverse Transfer Capacitance	C_{rss}			280		

/ Electrical Characteristic Curve

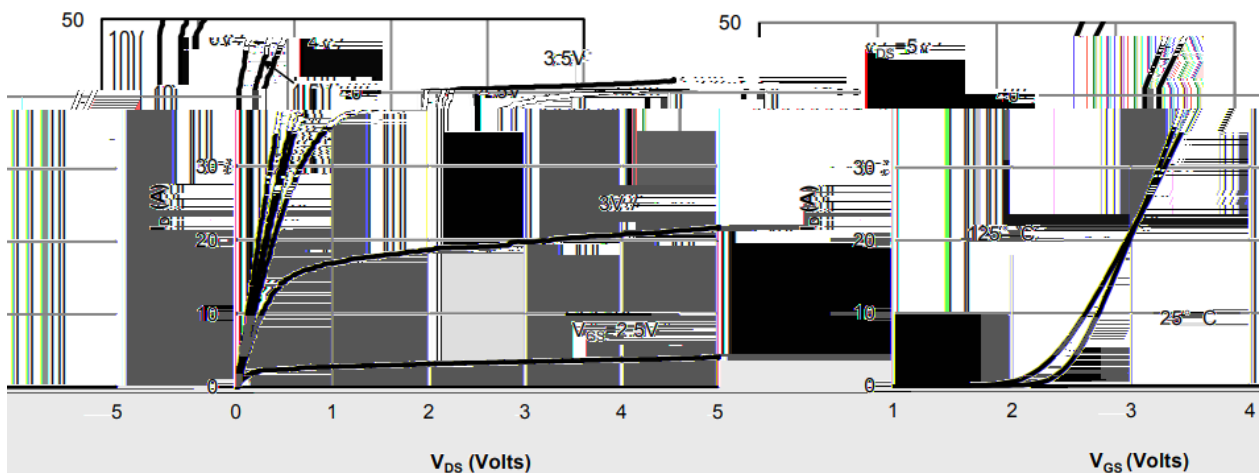


Figure 1: On-Region Characteristics

Figure 2: Transfer Characteristics

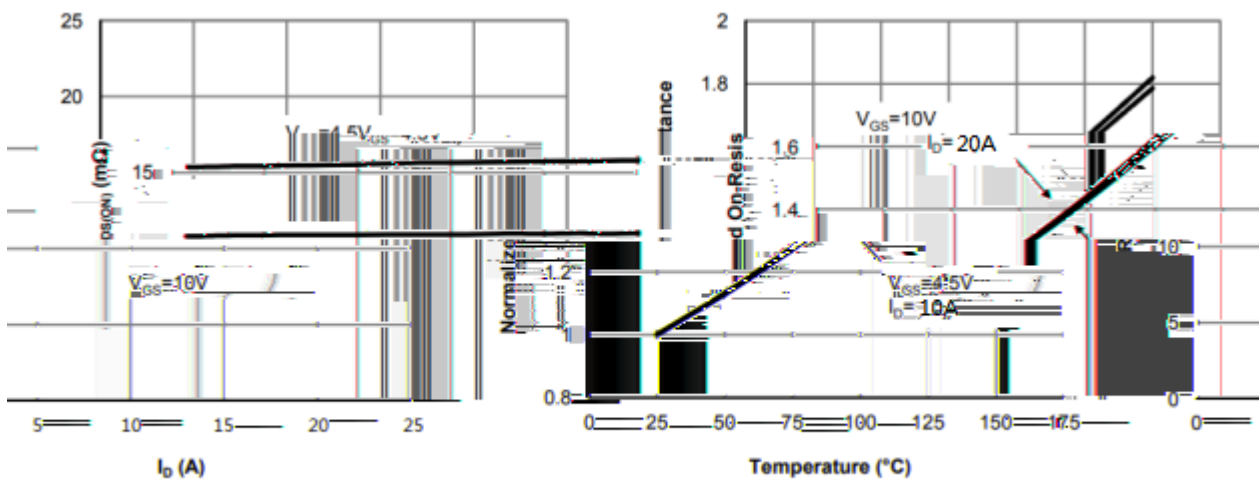


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

Figure 4: On-Resistance vs. Junction Temperature

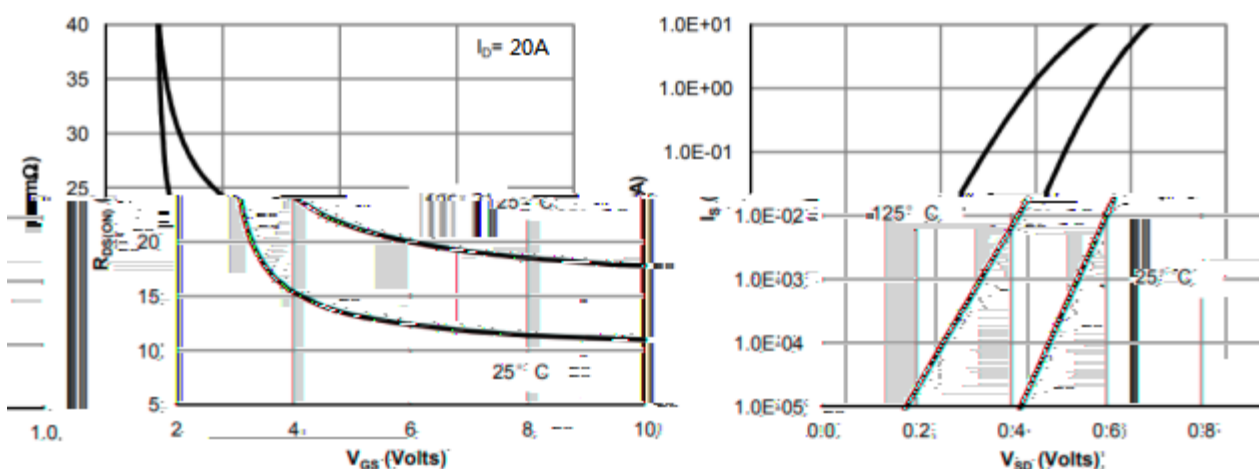
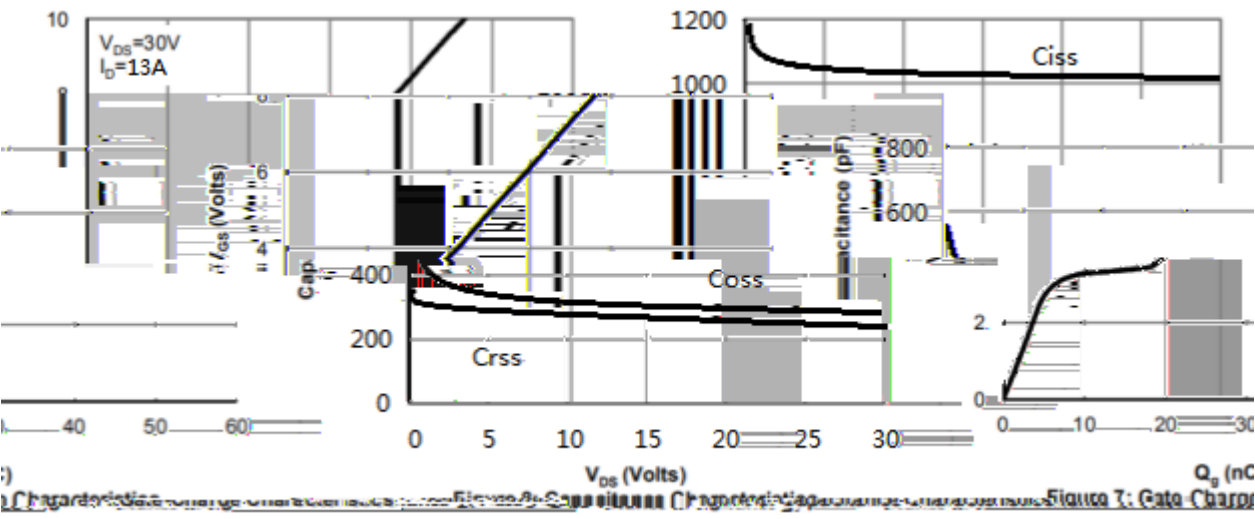


Figure 5: On-Resistance vs. Drain-Source Voltage

Figure 6: Power Dissipation vs. Body Diode Current

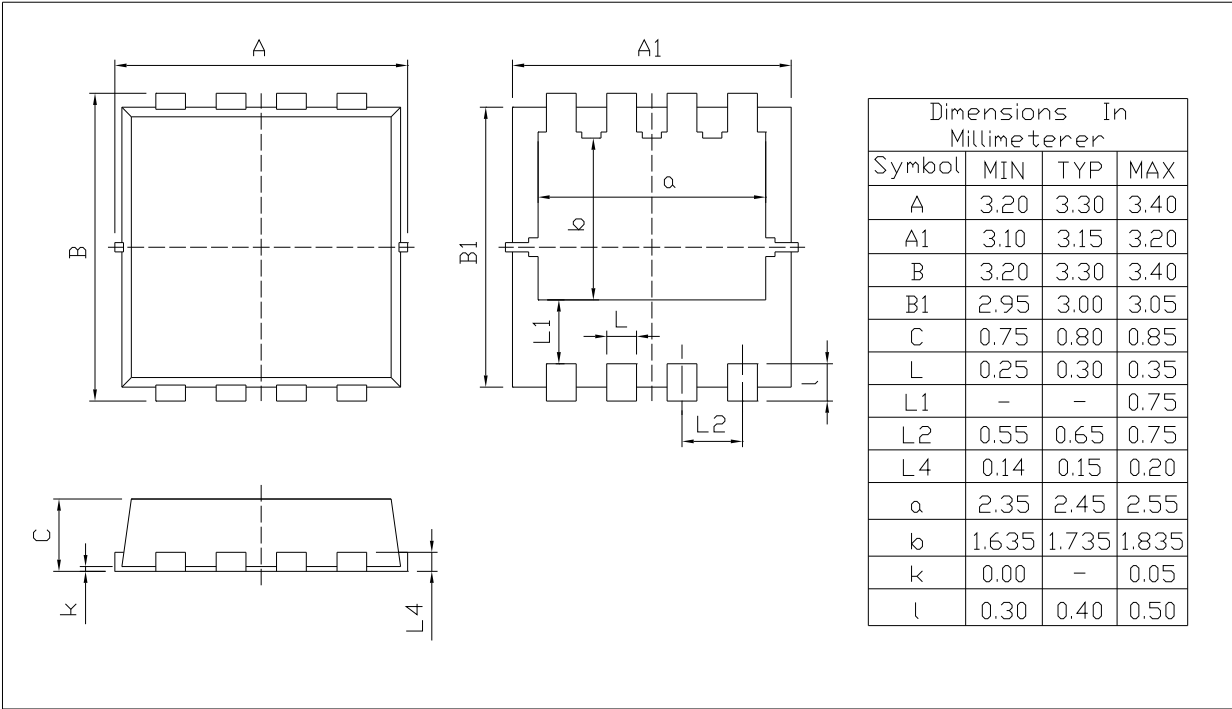
/ Electrical Characteristic Curve



/ Package Dimensions

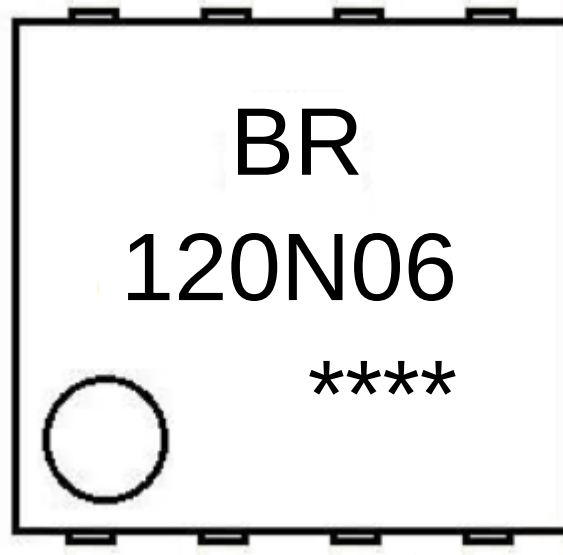
PDFN3X3A-8L

Unit:mm



Rev.00 202011

/ Marking Instructions



BR

120N06

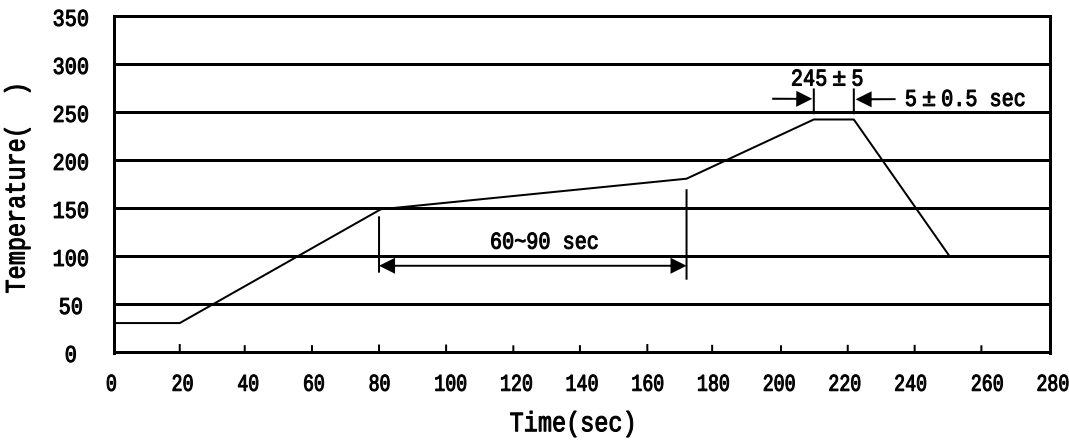
Note:

BR: Company Code

120N06: Product Type Code

****: Lot No. Code, code change with Lot No

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

150 180

60 90sec;

1.Preheating:150~180 , Time:60~90sec.
- 2

245±5

5±0.5sec;

2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5℃ Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
PDFN3×3A-8L	5,000	2	10,000	6	60,000	13 ×12	360×360×50	380×335×366

/ Notices